NSN 5962-01-339-5648

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-339-5648

Overall Length:	
0.840 inches	
Overall Height:	
0.400 inches	
Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches and 0.310 inches	
Body Height:	
Between 0.140 inches and 0.185 inches	
Maximum Power Dissipation Rating:	
739.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
Radar set an/sps-40d	
Features Provided:	
Hermetically sealed and burn in and monolithic and bipolar and programmed	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
6 input	
Case Outline Source And Designator:	
D-2 mil-m-38510	
Current Rating Per Characteristic:	
130.00 milliamperes supply	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
7.0 volts power source	
Time Rating Per Chacteristic:	
80.00 nanoseconds propagation delay time, high to low level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay	vel
output	
Memory Device Type:	
Prom	
Memory Capacity:	

Unknown

NSN 5962-01-339-5648

Memory Microcircuit - Page 2 of 2



Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0